

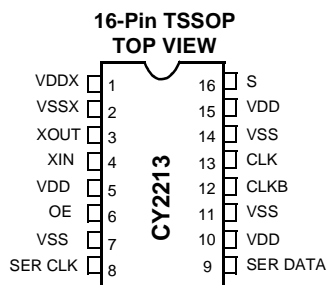
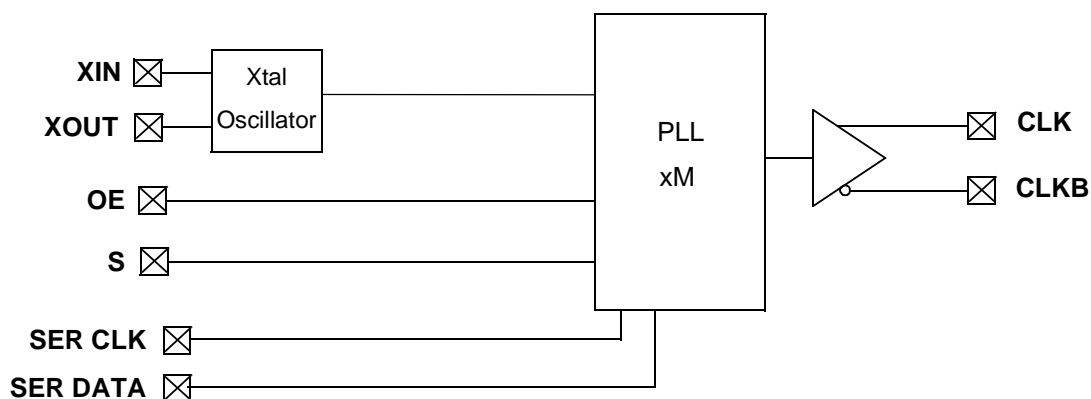


**CY2213**

# High-Frequency Programmable PECL Clock Generator

Features	Benefits
• LVPECL output	One pair of differential output drivers
• Default Select option	PLL multiplier select
• Serially configurable multiply ratios	8-bit P; 6-bit Q for high accuracy
• Output edge-rate control	Minimize EMI
• 16-pin TSSOP	Industry-standard, low-cost package saves on board space
• High frequency	125–400 MHz Extended output range for high-speed applications
• 3.3V operation	Enables application compatibility

## Logic Block Diagram



**Pin Summary**

Name	Pin	Description
VDDX	1	3.3V Power Supply for Crystal Driver
VSSX	2	Ground for Crystal Driver
XOUT	3	Reference Crystal Feedback
XIN	4	Reference Crystal Input
VDD	5	3.3 V Power Supply (All VDD pins must be tied directly together on board)
OE	6	Output Enable
VSS	7	Ground
SER CLK	8	Serial Interface Clock
SER DATA	9	Serial Interface Data
VDD	10	3.3V Power Supply (All VDD pins must be tied directly together on board)
VSS	11	Ground
CLKB	12	LVPECL Output Clock (complement)
CLK	13	LVPECL Output Clock
VSS	14	Ground
VDD	15	3.3V Power Supply (All VDD pins must be tied directly together on board)
S	16	PLL Multiplier Select Input, Pull-Up Resistor Internal

**Select Function Table**

S	M (PLL Multiplier)	Example Input Crystal Frequency	CLK,CLKB
0	x16	25 MHz	400 MHz
1	x8	15.625 MHz	125 MHz

## CY2213 Two-Wire Serial Interface

### Introduction

The CY2213 has a two-wire serial interface designed for data transfer operations, and is used for programming the P and Q values for frequency generation.  $S_{clk}$  is the serial clock line controlled by the master device.  $S_{data}$  is a serial bidirectional data line. The CY2213 is a slave device and can either read or write information on the dataline upon request from the master device.

Figure 1 shows the basic bus connections between master and slave device. The buses are shared by a number of devices and are pulled high by a pull-up resistor.

### Serial Interface Specifications

Figure 2 shows the basic transmission specification. To begin and end a transmission, the master device generates a start signal (S) and a stop signal (P). Start (S) is defined as switching the  $S_{data}$  from HIGH to LOW while the  $S_{clk}$  is at HIGH. Similarly, stop (P) is defined as switching the  $S_{data}$  from LOW to HIGH while holding the  $S_{clk}$  HIGH. Between these two signals, data on  $S_{data}$  is synchronous with the clock on the  $S_{clk}$ . Data is allowed to change only at LOW period of clock, and

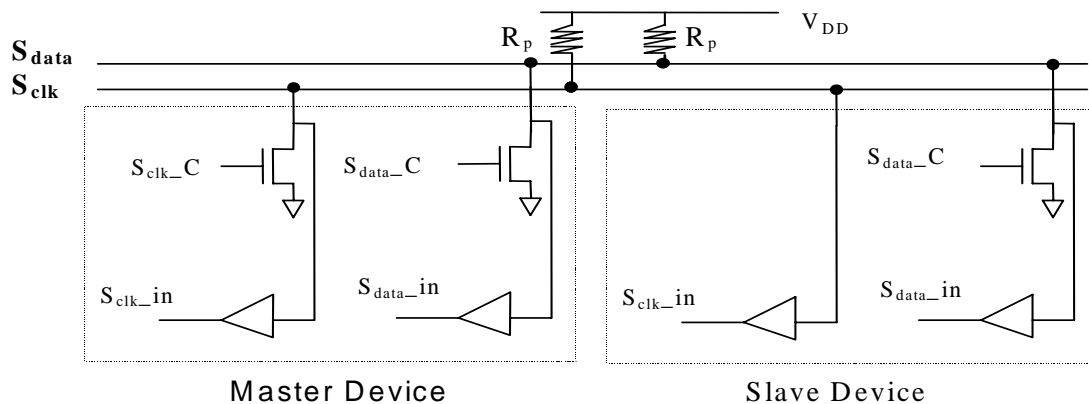
must be stable at the HIGH period of clock. To acknowledge, drive the  $S_{data}$  LOW before the  $S_{clk}$  rising edge and hold it LOW until the  $S_{clk}$  falling edge.

### Serial Interface Format

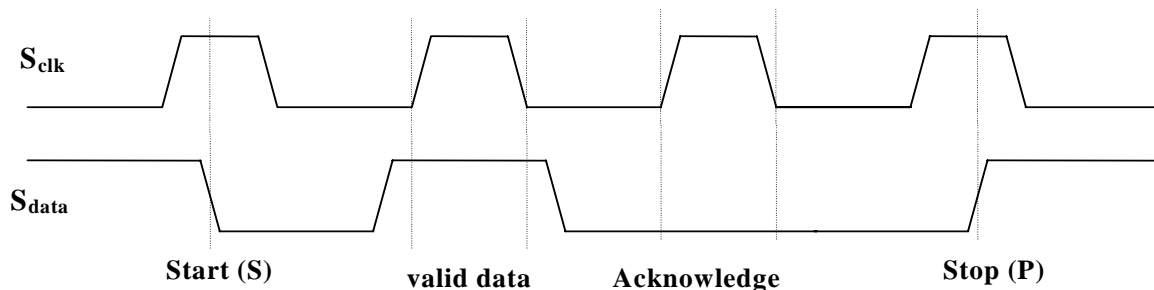
Each slave carries an address. The data transfer is initiated by a start signal (S). Each transfer segment is 1 byte in length. The slave address and the read/write bit are first sent from the master device after the start signal. The addressed slave device must acknowledge (Ack) the master device. Depending on the Read/Write bit, the master device will either write data into (logic 0) or read data (logic 1) from the slave device. Each time a byte of data is successfully transferred, the receiving device must acknowledge. At the end of the transfer, the master device will generate a stop signal (P).

### Serial Interface Transfer Format

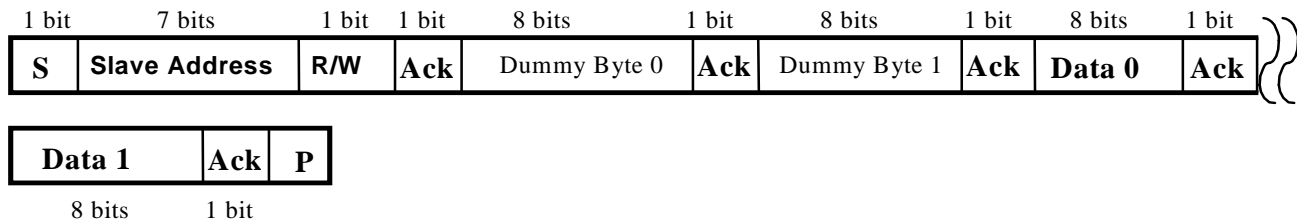
Figure 2 shows the serial interface transfer format used with the CY2213. Two dummy bytes must be transferred before the first data byte. The CY2213 has only three bytes of latches to store information, and the third byte of data is reserved. Extra data will be ignored.



**Figure 1. Device Connections**



**Figure 2. Serial Interface Specifications**



**Figure 3. CY2213 Transfer Format**

### Serial Interface Address for the CY2213

A6	A5	A4	A3	A2	A1	A0	R/W
1	1	0	0	1	0	1	0

### Serial Interface Programming for the CY2213

	b7	b6	b5	b4	b3	b2	b1	b0
Data0	QCNTBYP	SELPQ	Q<5>	Q<4>	Q<3>	Q<2>	Q<1>	Q<0>
Data1	P<7>	P<6>	P<5>	P<4>	P<3>	P<2>	P<1>	P<0>
Data2	Reserved	Reserved	Reserved	Reserved	Reserved	Reserved	Reserved	Reserved

To program the CY2213 using the two-wire serial interface, set the SELPQ bit HIGH. The default setting of this bit is LOW. The P and Q values are determined by the following formulas:

$$P_{\text{final}} = (P_{7..0} + 3) * 2$$

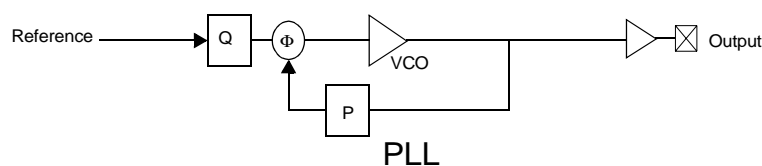
$$Q_{\text{final}} = Q_{5..0} + 2$$

If the QCNTBYP bit is set HIGH, then  $Q_{\text{final}}$  defaults to a value of 1. The default setting of this bit is LOW.

If the SELPQ bit is set LOW, the PLL multipliers will be set using the values in the Select Function Table.

CyClocksRT™ has been developed to generate P and Q values for stable PLL operation. For software details please contact [timingtech@cypress.com](mailto:timingtech@cypress.com).

### PLL frequency = Reference x P/Q = Output



**Figure 4. PLL Block Diagram**

## Absolute Maximums

The following table reflects stress ratings only, and functional operation at the maximums are not guaranteed.

Parameter	Description	Min.	Max.	Unit
$V_{DD,ABS}$	Max. voltage on $V_{DD}$ , or $V_{DDX}$ with respect to ground	-0.5	4.0	V
$V_{I, ABS}$	Max. voltage on any pin with respect to ground	-0.5	$V_{DD}+0.5$	V

## Crystal Requirements

Requirements to use parallel mode fundamental xtal. External capacitors are required in the crystal oscillator circuit. Please refer to Application note titled: "Crystal Oscillator Topics" for details.

Parameter	Description	Min.	Max.	Unit
$X_F$	Frequency	10	30	MHz

## DC Operating Conditions.

Parameter	Description	Min.	Max.	Unit
$V_{DD}$	Supply voltage	3.00	3.60	V
$T_A$	Ambient operating temperature	0	70	°C
$V_{IL}$	Input signal low voltage at pin S		0.35	$V_{DD}$
$V_{IH}$	Input signal high voltage at pin S	0.65		$V_{DD}$
$R_{PUP}$	Internal pull-up resistance	10	100	k $\Omega$

## AC Operating Conditions

Parameter	Description	Min.	Max.	Unit
$f_{IN}$	Input frequency with driven reference	1	133	MHz
$f_{XTAL,IN}$	Input frequency with crystal input	10	30	MHz
$C_{IN,CMOS}$	Input capacitance at S pin <sup>[1]</sup>		10	pF

## 3.3V DC Device Characteristics

Parameter	Description	Min.	Typ.	Max.	Unit
$V_{OH}$	Output high voltage, referenced to $V_{DD}$	-1.02	-0.95	-0.88	V
$V_{OL}$	Output low voltage, referenced to $V_{DD}$	-1.81	-1.70	-1.62	V

## State Transition Characteristics

Specifies the maximum settling time of the CLK and CLKB outputs from device power-up. For  $V_{DD}$  and  $V_{DDX}$  any sequences are allowed to power-up and power-down the CY2213.

From	To	Transition Latency	Description
$V_{DD}/V_{DDX}$ On	CLK/CLKB Normal	3 ms	Time from $V_{DD}/V_{DDX}$ is applied and settled to CLK/CLKB outputs settled.

**Note:**

- Capacitance measured at Freq = 1 MHz, DC Bias = 0.9V, and VAC < 100 mV.

## AC Device Characteristics

Parameter	Description	Min.	Typ.	Max.	Unit
$t_{\text{CYCLE}}$	Clock cycle time	2.50 (400 MHz)		8.00 (125 MHz)	ns
$t_{\text{JCRMS}}$	Cycle-to-cycle RMS jitter			0.25%	% $t_{\text{CYCLE}}$
	At 125-MHz frequency			20	ps
	At 400-MHz frequency			6.25	ps
$t_{\text{JCPK}}$	Cycle-to-cycle jitter (pk-pk)			1.5%	% $t_{\text{CYCLE}}$
	At 125-MHz frequency			120	ps
	At 400-MHz frequency			37.5	ps
$t_{\text{JPRMS}}$	Period jitter RMS			0.25%	% $t_{\text{CYCLE}}$
	At 125-MHz frequency			20	ps
	At 400-MHz frequency			6.25	ps
$t_{\text{JPPK}}$	Period jitter (pk-pk)			2.0%	% $t_{\text{CYCLE}}$
	At 125-MHz frequency			160	ps
	At 400-MHz frequency			50	ps
$t_{\text{JLT}}$	Long term RMS Jitter ( $P < 20$ )			1.75%	% $t_{\text{CYCLE}}$
	At 125-MHz frequency			140	ps
	At 400-MHz frequency			43.75	ps
$t_{\text{JLT}}$	Long term RMS Jitter ( $20 \leq P < 40$ )			2.5%	% $t_{\text{CYCLE}}$
	At 125-MHz frequency			200	ps
	At 400-MHz frequency			62.5	ps
$t_{\text{JLT}}$	Long term RMS Jitter ( $40 \leq P < 60$ )			3.5%	% $t_{\text{CYCLE}}$
	At 125-MHz frequency			280	ps
	At 400-MHz frequency			87.5	ps
Phase Noise	Phase Noise at 10 kHz (x8 mode) @ 125 MHz	-107		-92	dBc
DC	Long-term average output duty cycle	45		55	%
$t_{\text{DC,ERR}}$	Cycle-cycle duty cycle error at x8 with 15.625-MHz input			70	ps
$t_{\text{CR}}, t_{\text{CF}}$	Output rise and fall times (measured at 20% – 80% of $V_{\text{OHmin}}$ and $V_{\text{OLmax}}$ )	100		400	ps
$\text{BW}_{\text{LOOP}}$	PLL Loop Bandwidth	50 kHz (-3dB)		8 MHz (-20dB)	

## Functional Specifications

### Crystal Input

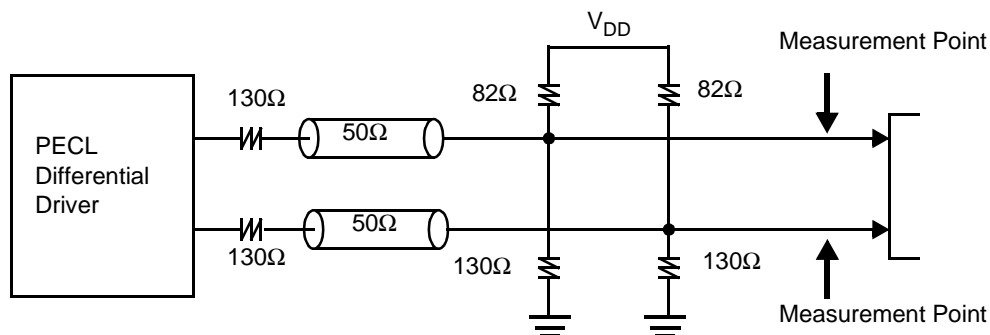
The CY2213 receives its reference from an external crystal. Pin XIN is the reference crystal input, and pin XOUT is the reference crystal feedback. The parameters for the crystal are given on page 5 of this data sheet. The oscillator circuit requires external capacitors. Please refer to Application note "Crystal Oscillator Topics" for details.

### Select Input

There is only one select input, pin S. This pin selects the frequency multiplier in the PLL, and is a standard LVCMOS input. The S pin has an internal pull-up resistor. The multiplier selection is given on page 2 of this data sheet.

### PECL Clock Output Driver

Figure 5 shows the clock output driver.



**Figure 5. Output Driver**

The PECL differential driver is designed for low-voltage, high-frequency operation. It significantly reduces the transient switching noise and power dissipation when compared to conventional CMOS drivers. The nominal value of the channel impedance is  $50\Omega$ . The pull-up and pull-down resistors provide matching channel termination. The combination of the differential driver and the output network determines the voltage swing on the channel. The output clock is specified at the measurement point indicated in *Figure 5*.

## Signal Waveforms

A physical signal that appears at the pins of the device is deemed valid or invalid depending on its voltage and timing

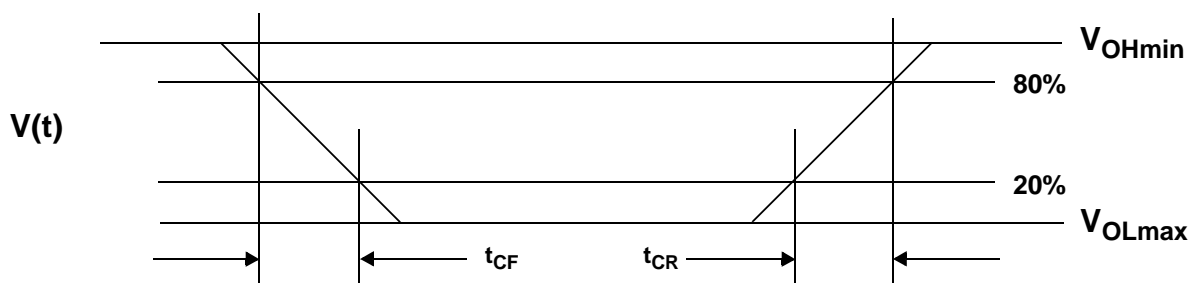
relations with other signals. This section defines the voltage and timing waveforms for the input and output pins of the CY2213. The Device Characteristics tables list the specifications for the device parameters that are defined here.

Input and Output voltage waveforms are defined as shown in *Figure 6*. Rise and fall times are defined as the 20% and 80% measurement points of  $V_{OHmin} - V_{OLmax}$ .

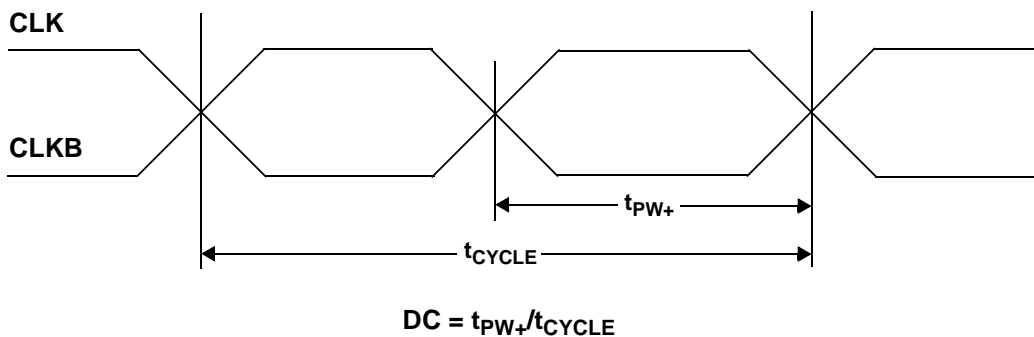
The device parameters are defined in *Table 1*. *Figure 7* shows the definition of long-term duty cycle, which is simply the CLK waveform high-time divided by the cycle time (defined at the crossing point). Long-term duty cycle is the average over many (>10,000) cycles. DC is defined as the output clock long-term duty cycle.

**Table 1. Definition of Device Parameters**

Parameter	Definition
$V_{OH}$ , $V_{OL}$	Clock output high and low voltages
$V_{IH}$ , $V_{IL}$	$V_{DD}$ LVCMOS input high and low voltages
$t_{CR}$ , $t_{CF}$	Clock output rise and fall times



**Figure 6. Voltage Waveforms**


**Figure 7. Duty Cycle Jitter**

## Jitter

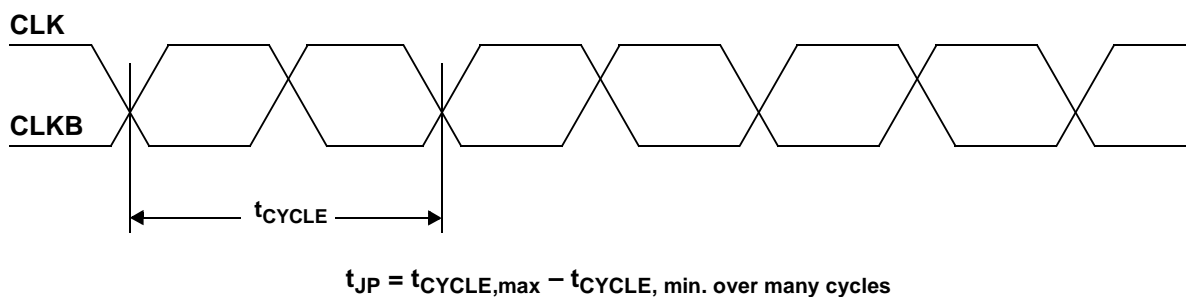
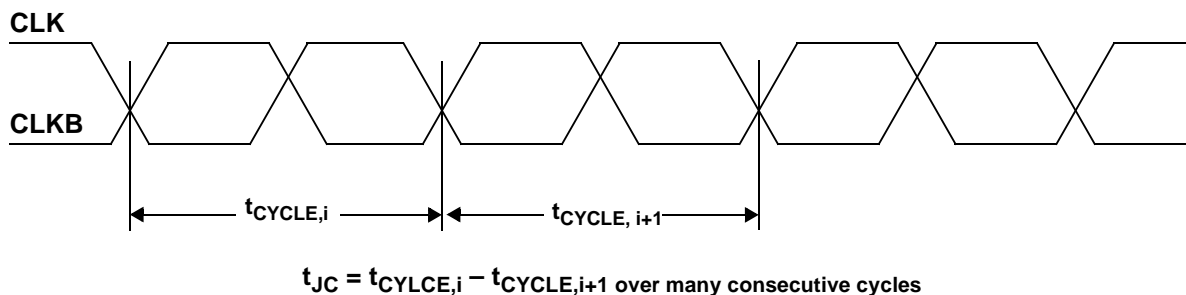
This section defines the specifications that relate to timing uncertainty (or jitter) of the input and output waveforms. *Figure 8* shows the definition of period jitter with respect to the falling edge of the CLK signal. Period jitter is the difference between the minimum and maximum cycle times over many cycles (typically 12800 cycles at 400 MHz). Equal requirements apply for rising edges of the CLK signal.  $t_{JP}$  is defined as the output period jitter.

*Figure 9* shows the definition of cycle-to-cycle jitter with respect to the falling edge of the CLK signal. Cycle-to-cycle jitter is the difference between cycle times of adjacent cycles over many cycles (typically 12800 cycles at 400 MHz). Equal re-

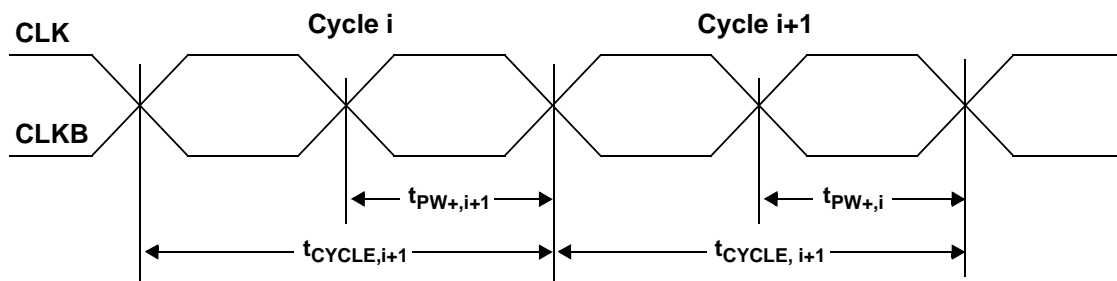
quirements apply for rising edges of the CLK signal.  $t_{JC}$  is defined as the clock output cycle-to-cycle jitter.

*Figure 10* shows the definition of cycle-to-cycle duty cycle error. Cycle-to-cycle duty cycle error is defined as the difference between high-times of adjacent cycles over many cycles (typically 12800 cycles at 400 MHz). Equal requirements apply to the low-times.  $t_{DC,ERR}$  is defined as the clock output cycle-to-cycle duty cycle error.

*Figure 11* shows the definition of long-term jitter error. Long-term jitter is defined as the accumulated timing error over many cycles (typically 12800 cycles at 400 MHz). It applies to both rising and falling edges.  $t_{JLT}$  is defined as the long-term jitter.

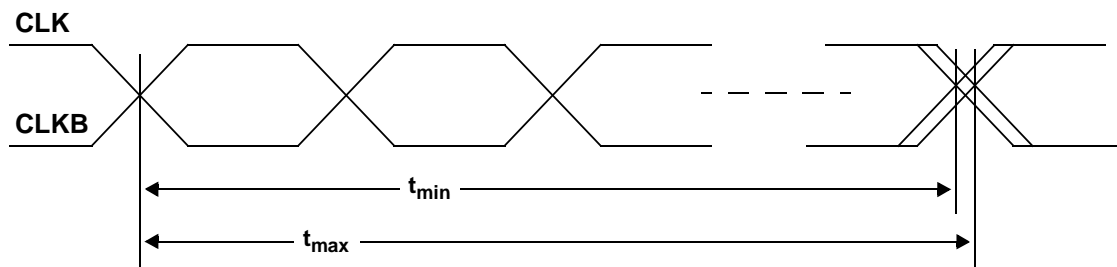

**Figure 8. Period Jitter**

**Figure 9. Cycle-to-cycle Jitter**





$$t_{DC,ERR} = t_{PW+,i} - t_{PW+,i+1} \text{ over many consecutive cycles}$$

Figure 10. Cycle-to-cycle Duty Cycle Error

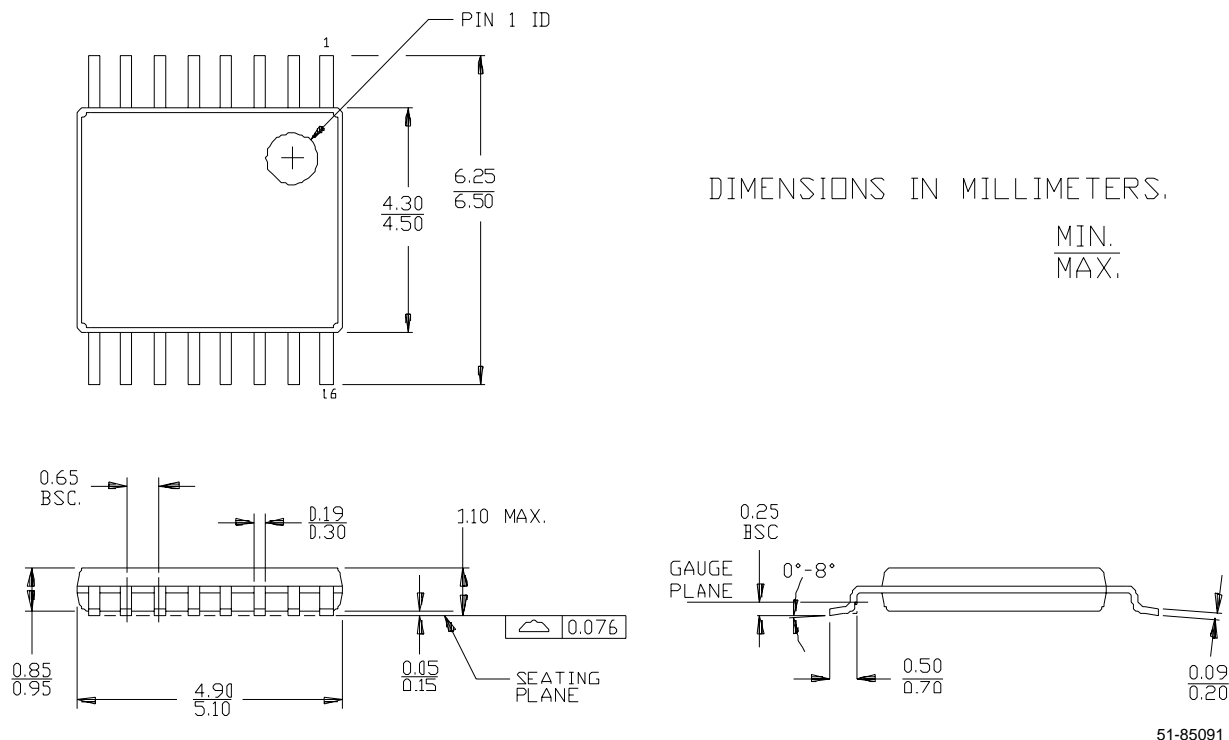


$$t_{JLT} = t_{max} - t_{min} \text{ over many cycles}$$

Figure 11. Long-Term Jitter

**Ordering Information**

Ordering Code	Package Name	Package Type	Operating Range
CY2213ZC-1	Z16	16-lead TSSOP	Commercial

**Package Information**
**16-Lead Thin Shrunk Small Outline Package (4.40 MM Body) Z16**


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Document Title: CY2213 High-Frequency Programmable PECL Clock Generator Document Number: 38-07263				
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**	113090	02/06/02	DSG	Change from Spec number: 38-01100 to 38-07263
*A	113512	05/24/02	CKN	Added PLL Block Diagram (Figure 4) and PLL frequency equation to page 4